



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 09/888,494
Applicant : Han-Chao LAI ET AL
Field : June 26, 2001
TC/A.U. : 2814
Examiner : Long Pham
Docket No. : 4425-154
Title : METHOD FOR FORMING A METAL OXIDE
SEMICONDUCTOR TYPE FIELD EFFECT
TRANSISTOR

Commissioner for Patent
P. O. Box 1450
Alexandria VA 22313-1450

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RESPONSE

Sir:

In response to the Office Action of July 1, 2003, please reconsider the above-identified application as follows:

This present amendment is in response to the Office Action mailed July 01, 2003, Claims 1-8 were rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al (U.S., Patent No. 6,130,454A) and Hsu et al (U.S. Patent No. 6,221,767B1); Claims 9-18 were rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner